



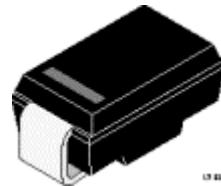
# Schottky Diode (FH1N5822)

肖特基二极管

## Features 特征:

- Ideal for surface mounted applications
- Low leakage current.
- For use in low voltage, high frequency inverters free wheeling, and polarity protection applications.

SMB ( DO-214AA )



## 3.0Ampere Schottky Barrier Rectifiers

### 3.0 安培肖特基势垒整流二极管

#### Absolute Maximum Ratings\* 最大绝对值

$T_A=25$  unless otherwise noted

Symbol 符号	Parameter 参数	Value	Units
$I_{F(AV)}$	Average Rectified Current 平均整流电流	3.0	A
$I_{FSM}$	Non-repetitive Peak Forward Surge Current 无重复正向峰值浪涌电流 8.3 ms single half-sine-wave superimposed on rated load	80	A
$P_D$	Total Device Dissipation 总耗散功率 Derate above 25	1.25 12.5	W MW/
$R_{JA}$	Thermal Resistance, Junction to Ambient 热阻	20	/W
$T_{STG}$	Storage Temperature Range 储存温度	-65 to +150	
$T_J$	Operating Junction Temperature 工作结温	-65 to +150	

\*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

#### Electrical Characteristics $T_A=25$ unless otherwise noted

Symbol 符号	Parameter 参数	Value	Units
$V_{RRM}$	Maximum Peak Repetitive Reverse Voltage 最大峰值反向电压	40	V
$V_{RMS}$	Maximum RMS Voltage	28	V
$V_R$	DC Reverse Voltage (Rated $V_R$ ) 反向电压	40	V
$I_{RM}$	Maximum Instantaneous Reverse Current 最大瞬间反向电流 $T_A=25$ @rated $V_R$ $T_A=100$	0.5 10	mA mA
$V_{FM}$	Maximum Instantaneous Forward Voltage 最大瞬间正向电压 @1.0A	500	mV
C	Typical Junction capacitance 典型结容	300	pF

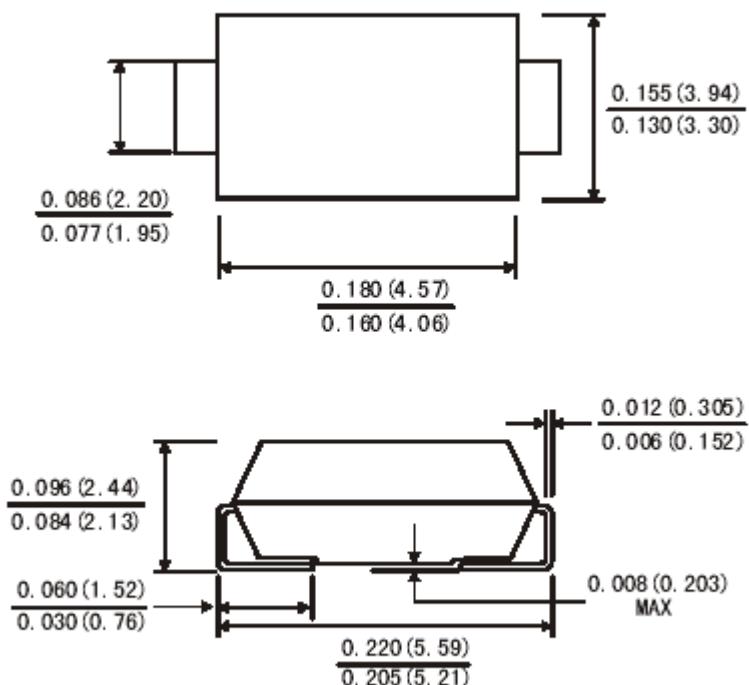


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## DO - 214AA Dimensions in INCHES(MILLIMETERS)

DO - 214AA 尺寸 英寸(毫米)

**DO214-AA**



Dimensions in inches and (millimeters)